

### **Degradation of 600-V 4H-SiC Schottky diodes under irradiation with 0,9 MeV electrons**

Lebedev, Alexander A.; Davydovskaja, K. S.; Kozlovski, Vitali V.; **Korolkov, Oleg**; **Sleptšuk, Natalja**; **Toompuu, Jana** 11th European Conference on Silicon Carbide and Related Materials : September 25-29, 2016, Porto Carras Grand Resort, Halkidiki, Greece : [poster session] 2016 / p. 49

### **Grid-frequency Vienna rectifier and isolated current-source DC-DC converters for efficient off-board charging of electric vehicles**

Rabkowski, Jacek; **Blinov, Andrei**; **Zinchenko, Denys**; Wrona, Grzegorz; Zdanowski, Mariusz 2020 22nd European Conference on Power Electronics and Applications (EPE'20 ECCE Europe), Lyon, France, 7-11 Sept. 2020 2020 / 10 p. : ill <https://doi.org/10.23919/EPE20ECCEurope43536.2020.9215772>

### **High-efficiency 312-kVA three-phase inverter using parallel connection of silicon carbide MOSFET power modules**

Colmenares, Juan; Pefitsis, Dimosthenis; **Rabkowski, Jacek** IEEE transactions on industry applications 2015 / p. 4664-4676 : ill <http://dx.doi.org/10.1109/TIA.2015.2456422>

### **Nano- and Micro-Scale simulations of Ge/3C-SiC and Ge/4H-SiC NN-heterojunction diodes**

**Rashid, Muhammad Haroon**; **Koel, Ants**; **Rang, Toomas** Silicon Carbide and Related Materials 2019 : 18th International Conference on Silicon Carbide and Related Materials 2019 (ICSCRM 2019), Kyoto, Japan, September 29 - October 4, 2019 Materials science forum 2020 / p. 490-496 <https://doi.org/10.4028/www.scientific.net/MSF.1004.490> [Conference proceedings at Scopus](#) [Article at Scopus](#)

### **Numerical simulations of wideband SiC N-N heterostructure diode**

**Patankar, Udayan Sunil**; **Koel, Ants**; **Pardy, Tamas** LAEDC 2020 : Latin American Electron Devices Conference, San José, Costa Rica, February 25-28, 2020 2020 / 4 p <https://doi.org/10.1109/LAEDC49063.2020.9073489>

### **SEU study of wideband heterostructure diode for particle detection**

**Patankar, Udayan Sunil**; **Koel, Ants** 2021 IEEE International Conference on Consumer Electronics (ICCE) 2021 / 4 p. : ill <https://doi.org/10.1109/ICCE50685.2021.9427613> [Conference Proceedings at Scopus](#) [Article at Scopus](#) [Article at WOS](#)

### **Short-circuit protection circuits for silicon-carbide power transistors**

Sadik, Diane-Perle; Colmenares, Juan; Tolstoy, Georg; **Rabkowski, Jacek** IEEE transactions on industrial electronics 2016 / p. 1995-2004 : ill <https://doi.org/10.1109/TIE.2015.2506628>

### **SiC schottky diode rectifier bridge represented as the diffusion-welded stack**

**Korolkov, Oleg**; **Land, Raul**; **Sleptšuk, Natalja**; **Toompuu, Jana**; **Rang, Toomas** 11th European Conference on Silicon Carbide and Related Materials : September 25-29, 2016, Porto Carras Grand Resort, Halkidiki, Greece : [poster session] 2016 / p. 42

### **Sintering of silicon carbide obtained by combustion synthesis**

Amirkhanyan, Narine; Kirakosyan, Hasmik; Zakaryan, Marieta; Zurnachyan, Alina; Rodriguez, Miguel Angel; Abovyan, L.; **Aydinyan, Sofiya** Ceramics international 2023 / p. 26129-26134 <https://doi.org/10.1016/j.ceramint.2023.04.233> [Journal metrics at Scopus](#) [Article at Scopus](#) [Journal metrics at WOS](#) [Article at WOS](#)